



Description

The FDS6675 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.



SOP-8
(CO-8)

$V_{DS} = -30V$ $I_D = -12A$

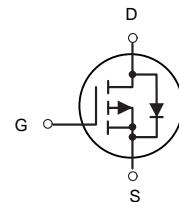
$R_{DS(ON)} < 13m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
FDS6675	SOP-8(SO-8)	HXY MOSFET	3000

Absolute Maximum Ratings($T_c=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	+20	V
$I_D@T_A=25^\circ C$	Drain Current ³ , $V_{GS} @ 10V$	-12	A
$I_D@T_A=70^\circ C$	Drain Current ³ , $V_{GS} @ 10V$	-9.1	A
I_{DM}	Pulsed Drain Current ¹	-40	A
$P_D@T_A=25^\circ C$	Total Power Dissipation	2.5	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C
R_{thj-a}	Maximum Thermal Resistance, Junction-ambient ³	50	°C/W

**Electrical Characteristics@T_j=25°C(unless otherwise specified)**

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250uA	-30	-	-	V
R _{Ds(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =-10V, I _D =-10A	-	10	13	mΩ
		V _{GS} =-4.5V, I _D =-6A	-	15	25	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250uA	-1	-	-2.5	V
g _{fs}	Forward Transconductance	V _{DS} =-10V, I _D =-10A	-	22	-	S
I _{DSS}	Drain-Source Leakage Current	V _{DS} =-24V, V _{GS} =0V	-	-	-10	uA
I _{GSS}	Gate-Source Leakage	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Q _g	Total Gate Charge	I _D =-6A V _{DS} =-15V V _{GS} =-4.5V	-	28	45	nC
Q _{gs}	Gate-Source Charge		-	7	-	nC
Q _{gd}	Gate-Drain ("Miller") Charge		-	11	-	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =-15V I _D =-1A R _G =3.3Ω V _{GS} =-10V	-	13	-	ns
t _r	Rise Time		-	10	-	ns
t _{d(off)}	Turn-off Delay Time		-	80	-	ns
t _f	Fall Time		-	37	-	ns
C _{iss}	Input Capacitance	V _{GS} =0V V _{DS} =-15V f=1.0MHz	-	2940	4700	pF
C _{oss}	Output Capacitance		-	290	-	pF
C _{rss}	Reverse Transfer Capacitance		-	210	-	pF
R _g	Gate Resistance	f=1.0MHz	-	6.2	12.4	Ω
V _{SD}	Forward On Voltage ²	I _S =-2.1A, V _{GS} =0V	-	-	-1.2	V
t _{rr}	Reverse Recovery Time	I _S =-10A, V _{GS} =0V, dI/dt=100A/μs	-	19	-	ns
Q _{rr}	Reverse Recovery Charge		-	6	-	nC

Notes:

- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in² copper pad of FR4 board, t ≤ 10s ; 125 °C/W when mounted on Min. copper pad.



Typical Characteristics

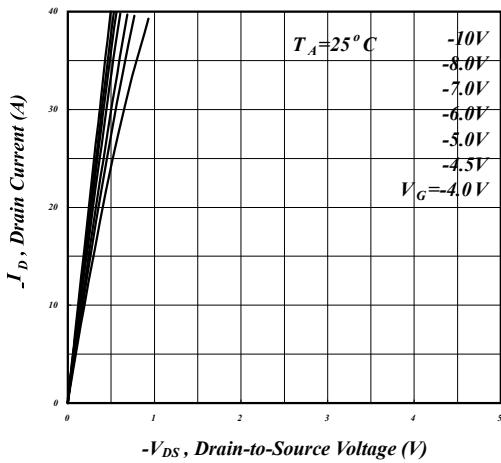


Fig 1. Typical Output Characteristics

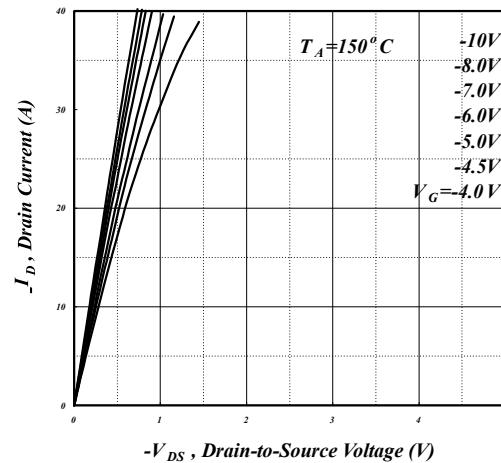


Fig 2. Typical Output Characteristics

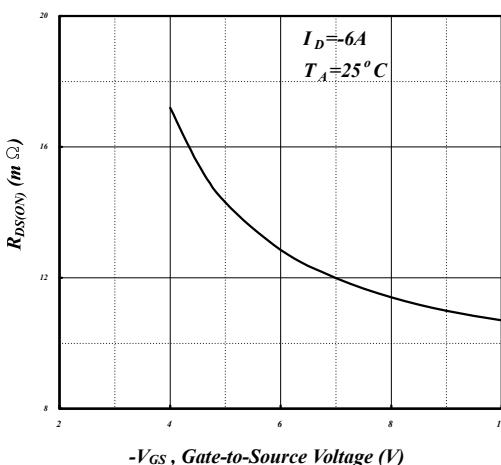


Fig 3. On-Resistance v.s. Gate Voltage

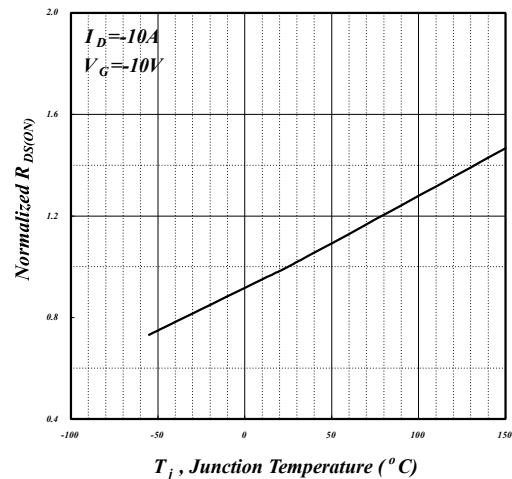
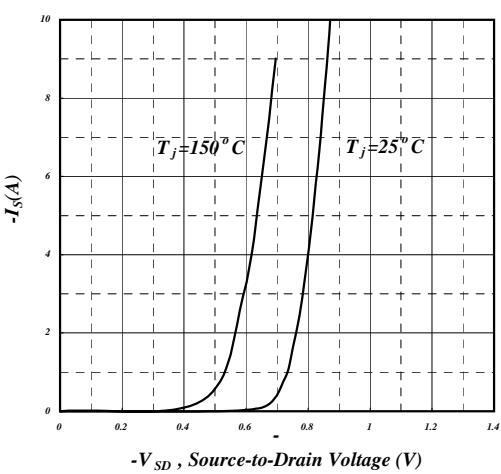


Fig 4. Normalized On-Resistance v.s. Junction Temperature



Reverse Diode

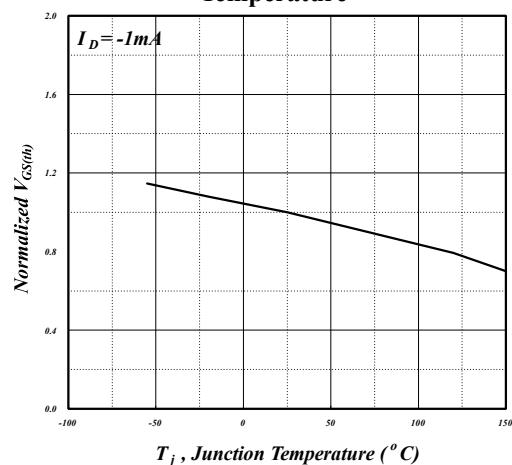
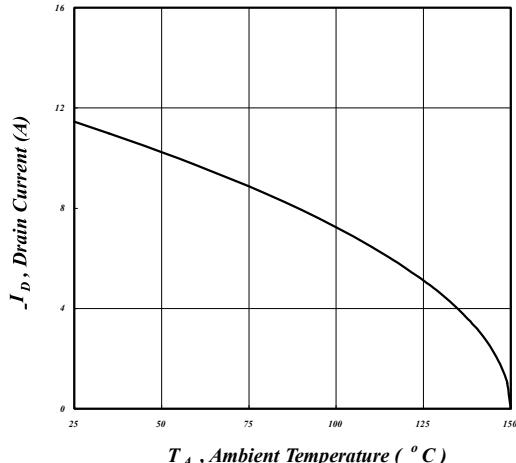
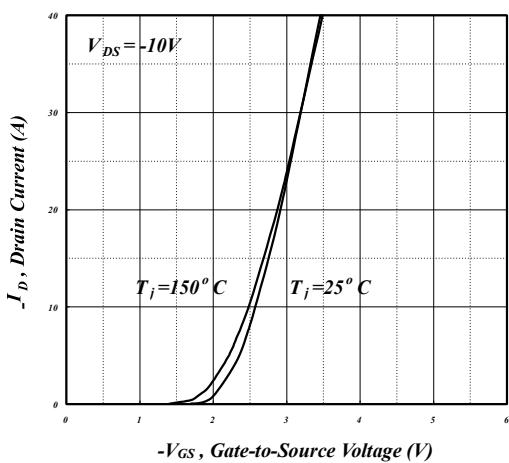
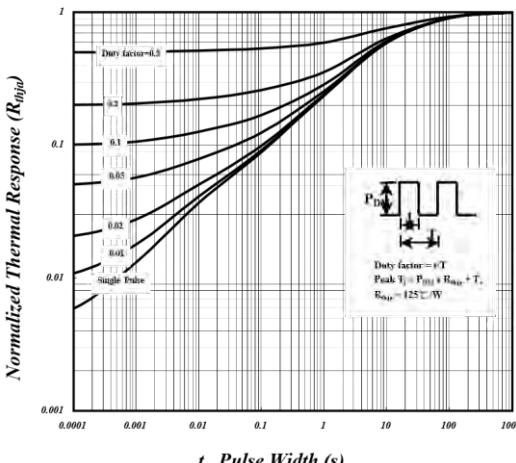
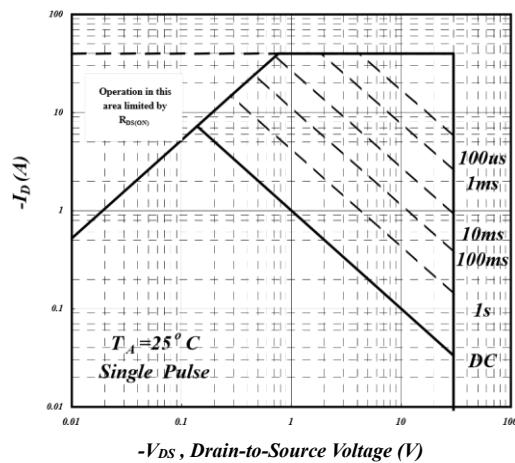
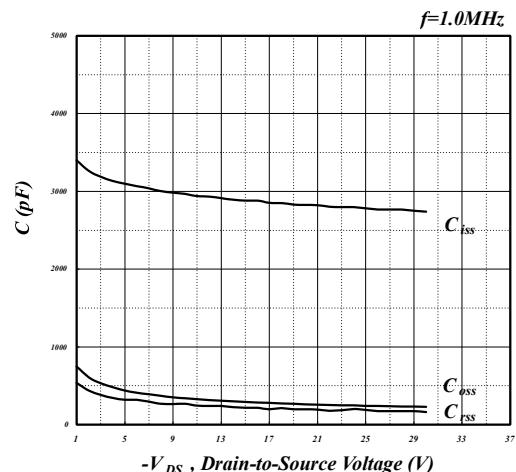
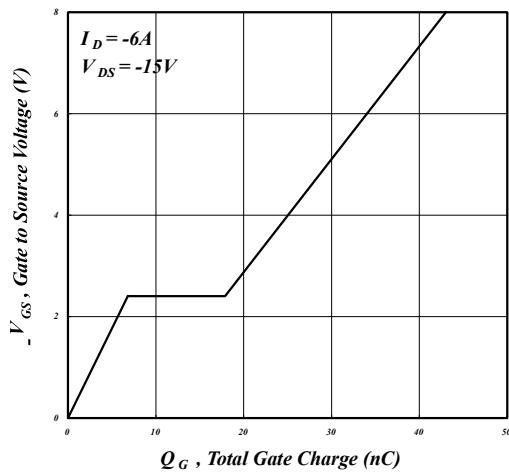
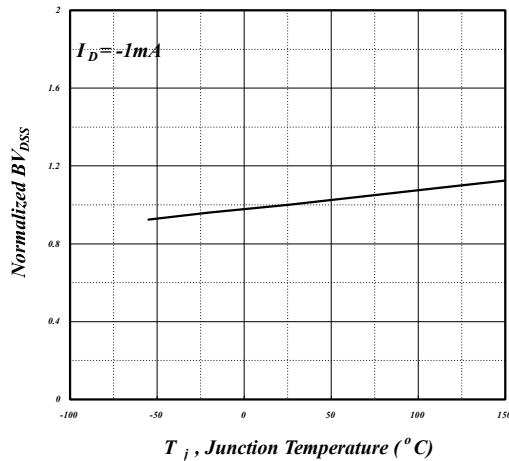


Fig 6. Gate Threshold Voltage v.s. Junction Temperature





**Fig 13. Normalized BV_{DSS} v.s.
JunctionTemperature**

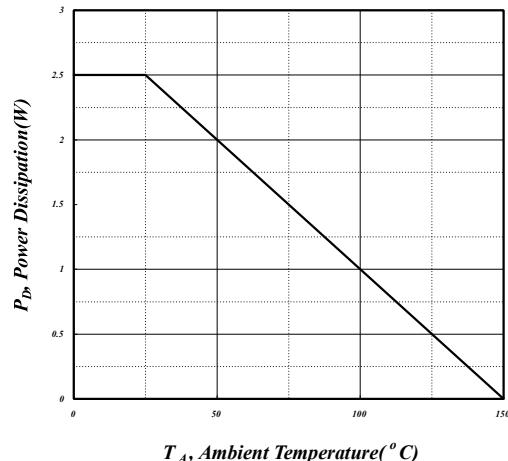


Fig 14. Total Power Dissipation

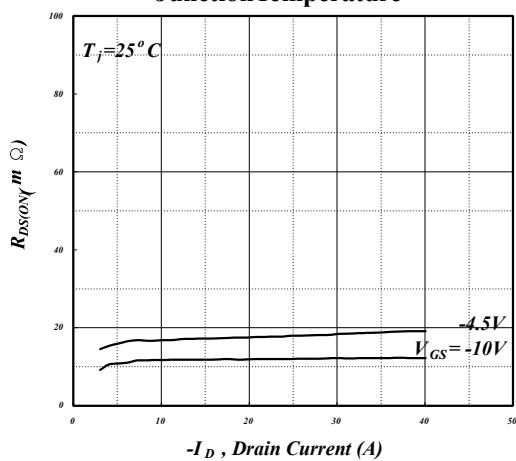
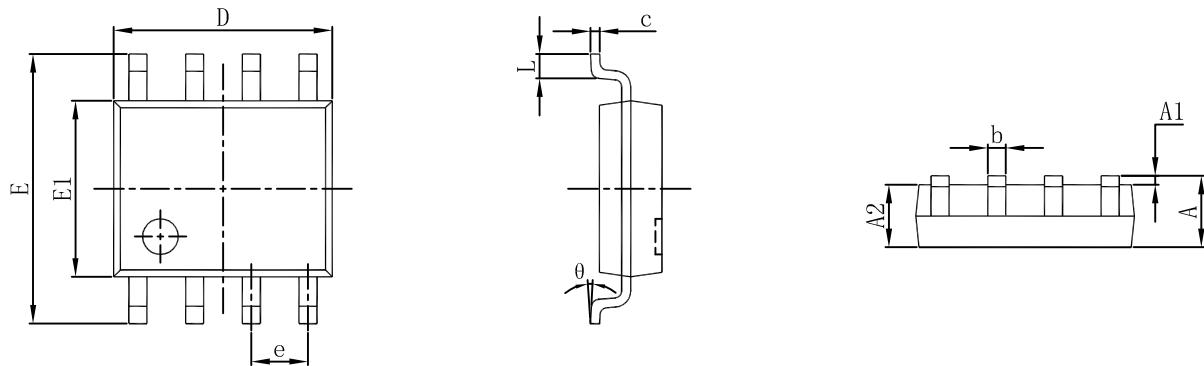


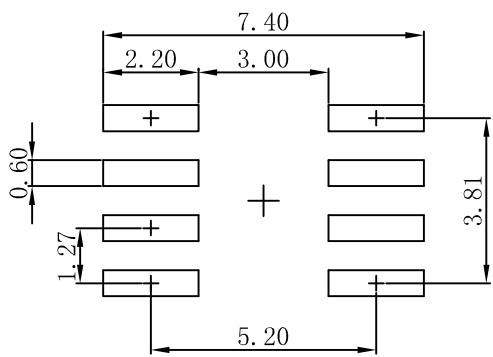
Fig 15. Typ. Drain-Source on State Resistance



SOP-8(SO-8) Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



Note:
1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.



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